## **General Purpose Transistor**

## **NPN Silicon**

### Features

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and **PPAP** Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V <sub>CEO</sub>	40	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	60	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	6.0	Vdc
Collector Current – Continuous	Ι <sub>C</sub>	200	mAdc

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

### THERMAL CHARACTERISTICS

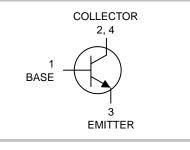
Characteristic	Symbol	Max	Unit
Total Device Dissipation (Note 1) $T_A = 25^{\circ}C$	PD	1.5 12	W mW/°C
Thermal Resistance Junction-to-Ambient (Note 1)	$R_{\theta JA}$	83.3	°C/W
Thermal Resistance Junction-to-Lead #4	$R_{\thetaJA}$	35	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

1. FR-4 with 1 oz and 713 mm<sup>2</sup> of copper area.



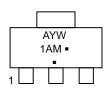
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### MARKING DIAGRAM



1AM = Specific Device Code А

- = Assembly Location
- = Year

Υ

= Work Week W

= Pb-Free Package

(Note: Microdot may be in either location)

### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
PZT3904T1G	SOT-223 (Pb-Free)	1,000 / Tape & Reel
SPZT3904T1G	SOT-223 (Pb-Free)	1,000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS (Note 2)				
Collector – Emitter Breakdown Voltage (Note 3) ( $I_C = 1.0 \text{ mAdc}, I_B = 0$ )	V <sub>(BR)CEO</sub>	40	-	Vdc
Collector – Base Breakdown Voltage ( $I_C = 10 \ \mu Adc$ , $I_E = 0$ )	V <sub>(BR)CBO</sub>	60	-	
Emitter-Base Breakdown Voltage ( $I_E = 10 \ \mu Adc$ , $I_C = 0$ )	V <sub>(BR)EBO</sub>	6.0	-	
Base Cutoff Current (V <sub>CE</sub> = 30 Vdc, V <sub>EB</sub> = 3.0 Vdc)	I <sub>BL</sub>	-	50	nAdc
Collector Cutoff Current (V <sub>CE</sub> = 30 Vdc, V <sub>EB</sub> = 3.0 Vdc)	I <sub>CEX</sub>	-	50	

#### **ON CHARACTERISTICS** (Note 3)

$ \begin{array}{l} \text{DC Current Gain (Note 2)} \\ (I_C = 0.1 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}) \\ (I_C = 1.0 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}) \\ (I_C = 10 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}) \\ (I_C = 50 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}) \\ (I_C = 100 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}) \end{array} $	H <sub>FE</sub>	40 70 100 60 30	 300 	-
	V <sub>CE(sat)</sub>		0.2 0.3	Vdc
$\begin{array}{l} \text{Base}-\text{Emitter Saturation Voltage (Note 3)} \\ (I_{C}=10 \text{ mAdc}, I_{B}=1.0 \text{ mAdc}) \\ (I_{C}=50 \text{ mAdc}, I_{B}=5.0 \text{ mAdc}) \end{array}$	V <sub>BE(sat)</sub>	0.65 -	0.85 0.95	Vdc

#### SMALL-SIGNAL CHARACTERISTICS

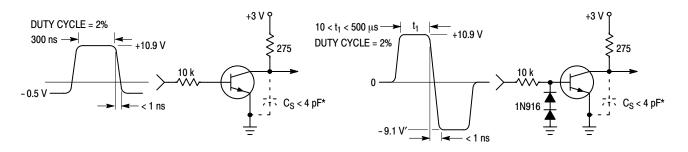
Current-Gain – Bandwidth Product ( $I_C = 10 \text{ mAdc}$ , $V_{CE} = 20 \text{ Vdc}$ , f = 100 MHz)	f <sub>T</sub>	300	-	MHz
Output Capacitance ( $V_{CB} = 5.0$ Vdc, $I_E = 0$ , f = 1.0 MHz)	C <sub>obo</sub>	-	5.0	pF
Input Capacitance ( $V_{EB}$ = 0.5 Vdc, $I_C$ = 0, f = 1.0 MHz)	C <sub>ibo</sub>	-	8.0	
Input Impedance (V <sub>CE</sub> = 10 Vdc, I <sub>C</sub> = 1.0 mAdc, f = 1.0 kHz)	h <sub>ie</sub>	1.0	10	kΩ
Voltage Feedback Ratio ( $V_{CE}$ = 10 Vdc, $I_C$ = 1.0 mAdc, f = 1.0 kHz)	h <sub>re</sub>	0.5	8.0	X 10 <sup>-4</sup>
Small-Signal Current Gain (V <sub>CE</sub> = 10 Vdc, I <sub>C</sub> = 1.0 mAdc, f = 1.0 kHz)	h <sub>fe</sub>	100	400	-
Output Admittance ( $V_{CE}$ = 10 Vdc, $I_C$ = 1.0 mAdc, f = 1.0 kHz)	h <sub>oe</sub>	1.0	40	μMhos
Noise Figure (V <sub>CE</sub> = 5.0 Vdc, I <sub>C</sub> = 100 $\mu$ Adc, R <sub>S</sub> = 1.0 kΩ, f = 1.0 kHz)	nF	-	5.0	dB

#### SWITCHING CHARACTERISTICS

Delay Time	(V <sub>CC</sub> = 3.0 Vdc, V <sub>BE</sub> = -0.5 Vdc,	t <sub>d</sub>	-	35	ns
Rise Time	$I_{\rm C} = 10 \text{ mAdc}, I_{\rm B1} = 1.0 \text{ mAdc})$	t <sub>r</sub>	_	35	
Storage Time	(V <sub>CC</sub> = 3.0 Vdc,	t <sub>s</sub>	_	200	
Fall Time	$I_{C} = 10 \text{ mAdc}, I_{B1} = I_{B2} = 1.0 \text{ mAdc})$	t <sub>f</sub>	-	50	

2. FR–5 = 1.0  $\times$  0.75  $\times$  0.062 in.

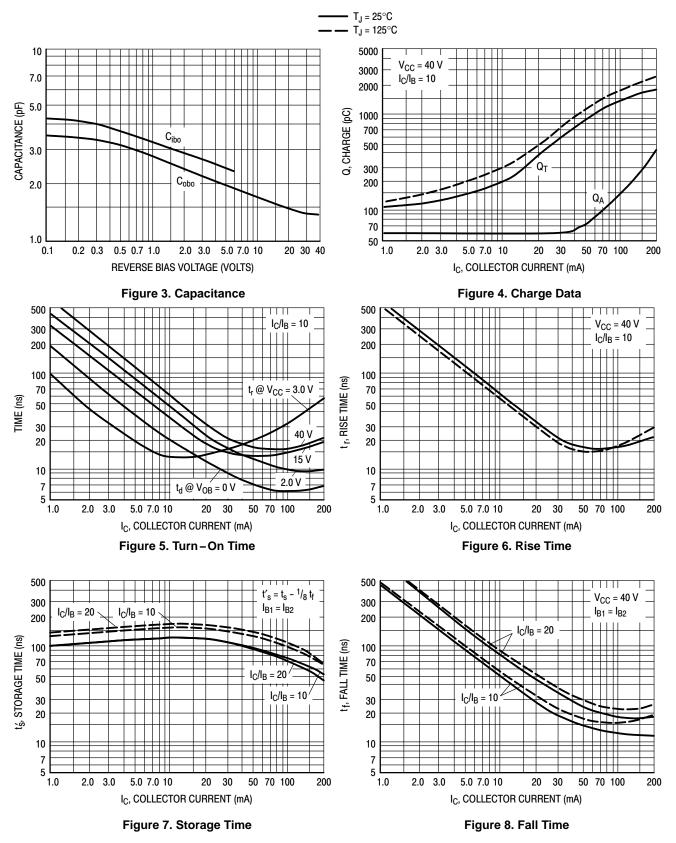
3. Pulse Test: Pulse Width  $\leq$  300 µs, Duty Cycle  $\leq$  2.0%.



\* Total shunt capacitance of test jig and connectors

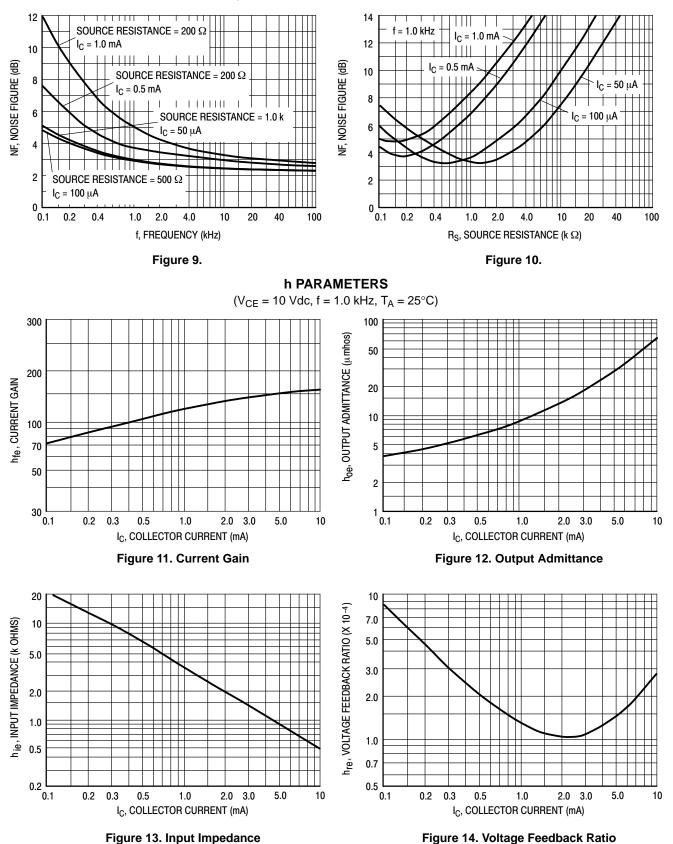
Figure 1. Delay and Rise Time Equivalent Test Circuit Figure 2. Storage and Fall Time Equivalent Test Circuit

### **TYPICAL TRANSIENT CHARACTERISTICS**

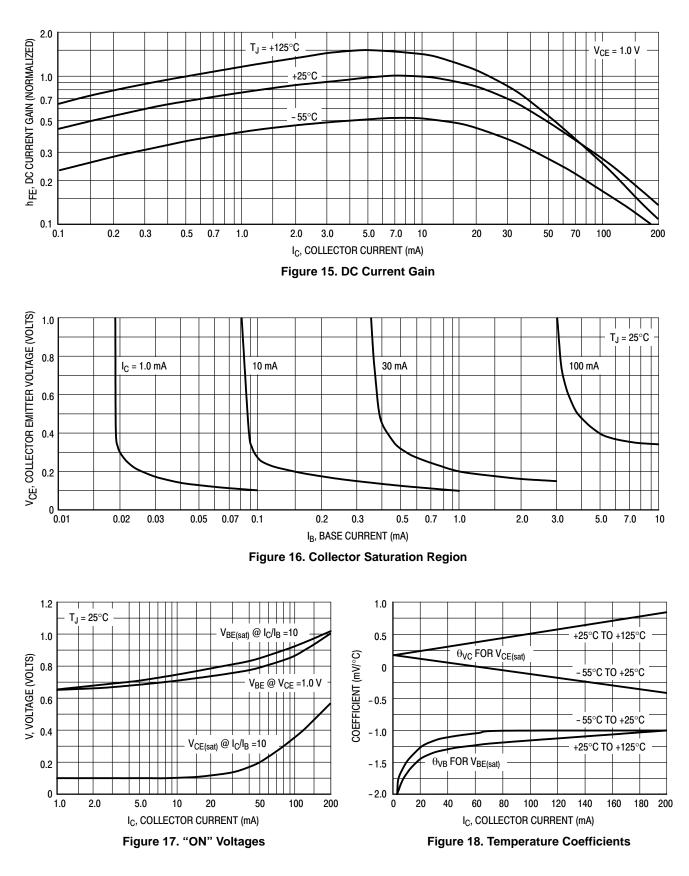


#### TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE VARIATIONS

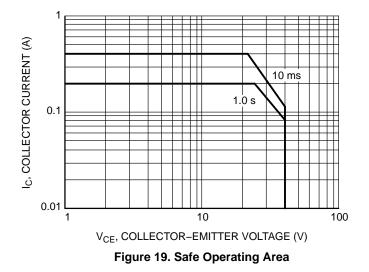
(V<sub>CE</sub> = 5.0 Vdc, T<sub>A</sub> = 25°C, Bandwidth = 1.0 Hz)



### **TYPICAL STATIC CHARACTERISTICS**



### **TYPICAL CHARACTERISTICS**



DATE 02 OCT 2018

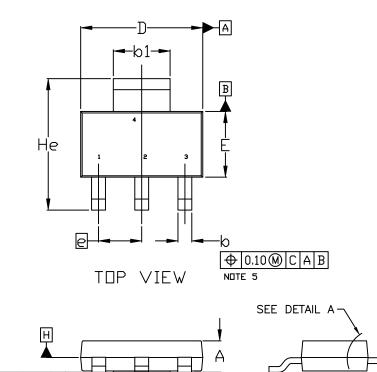




SCALE 1:1

0.10 C

A1



-11

SIDE VIEW

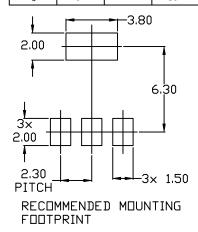
DETAIL A

NDTES:

SOT-223 (TO-261) CASE 318E-04 ISSUE R

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. DIMENSIONS D & E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.200MM PER SIDE.
- 4. DATUMS A AND B ARE DETERMINED AT DATUM H.
- 5. ALLS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST PDINT OF THE PACKAGE BODY.
- 6. POSITIONAL TOLERANCE APPLIES TO DIMENSIONS 6 AND 61.

	MILLIMETERS			
DIM	MIN.	NDM.	MAX.	
A	1.50	1.63	1.75	
A1	0.02	0.06	0.10	
b	0.60	0.75	0.89	
b1	2.90	3.06	3.20	
с	0.24	0.29	0.35	
D	6.30	6.50	6.70	
E	3.30	3.50	3.70	
e		2.30 BSC		
L	0.20			
L1	1.50	1.75	2.00	
He	6.70	7.00	7.30	
θ	0*		10*	



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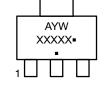
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#### SOT-223 (TO-261) CASE 318E-04 ISSUE R

#### DATE 02 OCT 2018

STYLE 1: PIN 1. BASE 2. COLLECTOR 3. EMITTER 4. COLLECTOR	STYLE 2: PIN 1. ANODE 2. CATHODE 3. NC 4. CATHODE	STYLE 3: PIN 1. GATE 2. DRAIN 3. SOURCE 4. DRAIN	STYLE 4: PIN 1. SOURCE 2. DRAIN 3. GATE 4. DRAIN	STYLE 5: PIN 1. DRAIN 2. GATE 3. SOURCE 4. GATE
STYLE 6: PIN 1. RETURN 2. INPUT 3. OUTPUT 4. INPUT	STYLE 7: PIN 1. ANODE 1 2. CATHODE 3. ANODE 2 4. CATHODE	STYLE 8: CANCELLED	Style 9: Pin 1. Input 2. Ground 3. Logic 4. Ground	STYLE 10: PIN 1. CATHODE 2. ANODE 3. GATE 4. ANODE
STYLE 11: PIN 1. MT 1 2. MT 2 3. GATE 4. MT 2	Style 12: Pin 1. Input 2. Output 3. NC 4. Output	STYLE 13: PIN 1. GATE 2. COLLECTOR 3. EMITTER 4. COLLECTOR		

### GENERIC MARKING DIAGRAM\*



- A = Assembly Location
- Y = Year
- W = Work Week
- XXXXX = Specific Device Code
- = Pb-Free Package
- (Note: Microdot may be in either location) \*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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